NSN 5962-00-328-0131

Memory Microcircuit - Page 1 of 1



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Body Length:
Between 0.240 inches and 0.290 inches
Body Width:
Between 0.240 inches and 0.260 inches
Body Height:
Between 0.030 inches and 0.070 inches
Maximum Power Dissipation Rating:
300.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Monolithic and hermetically sealed and positive outputs and negative outputs and high gain
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Flat pack
Input Circuit Pattern:
2 input
Case Outline Source And Designator:
T0-91 joint electron device engineering council
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
22.5 volts power source
Time Rating Per Chacteristic:
60.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
10 flat leads
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli

Fiig:

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